

ABSTRACT OF THE DISCLOSURE

The invention provides an active matrix display device in which active elements are formed on a first substrate, wiring lines are formed on a second substrate, an element chip having at least one active element is peeled off from the first substrate and is then transferred onto the second substrate, electro-optical elements are formed on a third substrate, and the second substrate adheres to the third substrate. The invention also provides a method of electrically connecting the active elements of the element chip to the wiring lines of the second substrate and of electrically connecting the active elements of the element chip to the electro-optical elements of the third substrate in a thin film transistor display device in which the active elements are thin film transistors.